EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	18666	(LDMOS$2 or LD-MOS$2 or (LD adj MOS$3) or LDMOSFET$1 or LD-MOSFET$1 or (LD adj MOSFET$1)) or (lateral$4 adj diffus$5 adj metal adj oxide adj semiconduct$4) or (lateral$4 adj diffus$5 adj (MOS$3 or MOSFET $1)) or (LDDMOS$2 or LDD-MOS$2 or (LDD adj MOS$3) or LDDMOSFET$1 or LDD-MOSFET$1 or (LDD adj MOSFET$1)) or ((lateral$4 adj double adj diffus$5 adj metal adj oxide adj semiconduct$4) or (lateral$4 adj double-diffus$5 adj metal adj oxide adj semiconduct$4)) or (lateral$4 adj double adj diffus$5 adj (MOS$3 or MOSFET$1)) or (lateral$4 near7 (metal adj oxide adj semiconduct$4)) or (lateral $4 near7 (MOS or MOSFET $1 or NMOS or NMOSFET $1 or PMOS or PMOSFET $1)) or (LDPMOS$2 or LD-PMOS$2 or (LD adj PMOS $3) or LDPMOSFET$1 or LD-PMOSFET$1 or (LD adj PMOSFET$1)) or (LDNMOS $2 or LD-NMOS$2 or (LD adj NMOS$3) or LDNMOSFET$1 or LD-NMOSFET$1 or (LD adj NMOSFET$1)) or (lateral $4 near7 (DMOS or DMOSFET$1)) or (lateral $4 adj8 (MOS or MOSFET $1 or NMOS or NMOSFET $1 or PMOS or PMOSFET $1 or FET$1 or transistor $1 or IGFET$1 or (insulat $5 adj gate adj field adj effect adj transistor$1)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:07

L2	3242700	gate$1 or electrode$1	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:11
L3	843756	(field adj (oxide$1 or isolat$5)) or LOCOS$2 or trench$2 or STI$1 or (shallow adj trench$2 adj isolat$5)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:11
L4	1672	implant$8 with (silicon or Si or "Si" or Ge or "Ge" or germanium) with ((amorphous or amorph$9) near3 (region$1 or area$1 or part$1 or portion$1 or element$1))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:14
L5	39	diffus$8 with (ion$1 or dopant$1) with channel$3 with ((amorphous or amorph$9) near3 (region$1 or area$1 or part$1 or portion$1 or element$1))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:16
L6	1	1 and 2 and 3 and 4 and 5	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:16
L7	0	("2001/0049172").URPN.	USPAT	OR	OFF	2009/09/14 10:17
L8	214	diffus$8 same (ion$1 or dopant$1) same channel$3 same ((amorphous or amorph$9) near3 (region$1 or area$1 or part$1 or portion$1 or element$1))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:19
L9	18	8 and 1 and 2 and 3 and 4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:19
L10	13	9 and @ad <= "20010104"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:20

L11	1737	channel$3 near8 ((amorphous or amorph $9) near3 (region$1 or area$1 or part$1 or portion $1 or element$1))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:28
L12	9	1 and 2 and 3 and 4 and 11	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:29
L13	1	("6225154").PN.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:38
L14	2742	(438/197).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:42
L15	791	(438/286).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:43
L16	463	(438/291).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:44
L17	1516	(438/301).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:45
L18	157	(438/520).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:46
L19	506	(438/528).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:46
L20	565	(438/530).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:46
L21	1642	(438/585).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:47
L22	332	(438/542).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:47

9/14/09 10:48:51 AM
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